




	<h2 style="color: red;">FQD2N60CTF_F080</h2> <p>Hersteller-Teilenummer: FQD2N60CTF_F080</p> <hr/> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 600V 1.9A DPAK</p> <hr/> <p>Datenblätter:  FQD2N60CTF_F080.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 5000 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQD2N60CTF_F080
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 600V 1.9A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	5000 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	D-Pak
Verlustleistung (max)	2.5W (Ta), 44W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	1.9A (Tc)
Rds On (Max) @ Id, Vgs	4.7 Ohm @ 950mA, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	12nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	235pF @ 25V
Verpackung	Tape & Reel (TR)










































FQD2N60CTF_F080 ist neu im Original, Suche FQD2N60CTF_F080 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQD2N60CTF_F080 Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQD2N60CTF_F080: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQD2N60B FAIRCHI FQD2N60B FAIRCHI</p>	 <p>FQD2N60CTF-NL Fairchild/ON Semiconductor FQD2N60CTF-NL FAIRCHILD</p>	 <p>FQD2N60CTM-WS AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 1.9A</p>	 <p>FQD2N60CTF Fairchild/ON Semiconductor MOSFET N-CH 600V 1.9A DPAK</p>
 <p>FQD2N60CTM Fairchild/ON Semiconductor MOSFET N-CH 600V 1.9A DPAK</p>	 <p>FQD2N60CTF_F080 AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 1.9A DPAK</p>	 <p>FQD2N60CTM AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 1.9A DPAK</p>	 <p>FQD2N60CTF AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 1.9A DPAK</p>

heiße Teile

Mehr

 FQD20N06TM	 FQD20N06TM	 FQD24N08	 FQD24N08TF	 FQD24N08TF
 FQD24N08TM	 FQD24N08TM	 FQD2N100	 FQD2N100TM	 FQD2N100TM
 FQD2N30TF	 FQD2N40TM	 FQD2N40TM	 FQD2N50B	 FQD2N50C
 FQD2N50TF	 FQD2N50TF	 FQD2N50TM	 FQD2N50TM	 FQD2N60A
 FQD2N60C	 FQD2N60CTF	 FQD2N60CTF	 FQD2N60CTF-NL	 FQD2N60CTF_F080
 FQD2N60CTM	 FQD2N60CTM	 FQD2N60TM	 FQD2N60TM	 FQD2N65C
 FQD2N80TM	 FQD2N80TM	 FQD2N80TM-NL	 FQD2N90TF	 FQD2N90TF
 FQD2P25TF	 FQD2P25TM	 FQD30N06	 FQD30N06L	 FQD30N06LTF
 FQD30N06LTF	 FQD30N06LTM	 FQD30N06LTM	 FQD30N06TF	 FQD30N06TF
 FQD30N06TF_F080	 FQD30N06TF_F080	 FQD30N06TM	 FQD30N06TM	 FQD30P06

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